

6A, 50V - 1000V Standard Bridge Rectifier

FEATURES

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• Glass passivated chip junction

SEMICONDUCTOR

- Ideal for printed circuit board
- Reliable low cost construction
- UL Recognized File # E-326243
- RoHS Compliant

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application

MECHANICAL DATA

• Case: KBL

_ _ _ _ _ _ _ _

- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test

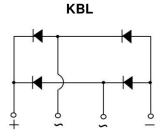
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- Polarity: As marked
- Weight: 5.60g (approximately)

| KEY PARAMETERS | | | |
|--------------------|-----------|------|--|
| PARAMETER | VALUE | UNIT | |
| I _F | 6 | А | |
| V _{RRM} | 50 - 1000 | V | |
| I _{FSM} | 175 | А | |
| T _{J MAX} | 150 | °C | |
| Package | KBL | | |
| Configuration | Quad | 1 | |







| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | | | | | | |
|--|---------------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|------------------|
| PARAMETER | SYMBOL | KBL 601G | KBL 602G | KBL 603G | KBL 604G | KBL 605G | KBL 606G | KBL 607G | UNIT |
| Marking code on the device | | KBL 601G | KBL 602G | KBL 603G | KBL 604G | KBL 605G | KBL 606G | KBL 607G | |
| Repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Reverse voltage, total rms value | V _{R(RMS)} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Forward current | I _F | | | | 6 | | | | Α |
| Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load | I _{FSM} | | | | 175 | | | | A |
| Rating for fusing (t<8.3ms) | l ² t | | | | 127 | | | | A ² s |
| Junction temperature | TJ | | | - ! | 55 to +1 | 50 | | | °C |
| Storage temperature | T _{STG} | | | - (| 55 to +1 | 50 | | | °C |



| THERMAL PERFORMANCE | | | |
|--|------------------|-----|------|
| PARAMETER | SYMBOL | ТҮР | UNIT |
| Junction-to-lead thermal resistance | R _{eJL} | 7.5 | °C/W |
| Junction-to-ambient thermal resistance | R _{eJA} | 13 | °C/W |

| ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted) | | | | | |
|--|-------------------------------|----------------|-----|-----|------|
| PARAMETER | CONDITIONS | SYMBOL | ТҮР | MAX | UNIT |
| Forward voltage per diode ⁽¹⁾ | $I_F = 3A, T_J = 25^{\circ}C$ | N | - | 1.0 | V |
| Forward voltage per diode | $I_F = 6A, T_J = 25^{\circ}C$ | V _F | - | 1.1 | V |
| Reverse current @ rated V_R per diode ⁽²⁾ | $T_J = 25^{\circ}C$ | I _R | - | 10 | μA |
| neverse current @ rated v _R per diode | T _J = 125°C | | - | 500 | μA |

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION

| ORDERING CODE ⁽¹⁾ | PACKAGE | PACKING |
|------------------------------|---------|------------|
| KBL60xG | KBL | 100 / Tray |

Notes:

1. "x" defines voltage from 50V(KBL601G) to 1000V(KBL607G)



INSTANTANEOUS REVERSE CURRENT (µA)

10

1

0.1

0.01

10 20 30

PEAK FORWARD SURGE CURRENT (A)

20 0

1

CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

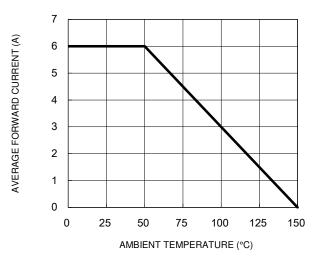


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

T₁=125°C

T_=25°C

60 70 80 90

PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

40 50

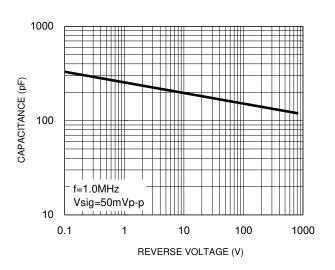
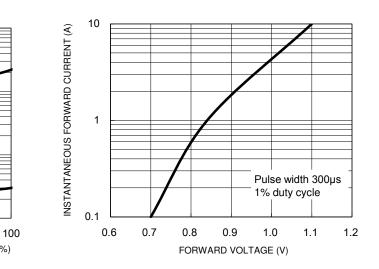


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



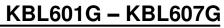
180 160 140 120 100 80 60 40

Fig.5 Maximum Non-Repetitive Forward Surge Current

1000

100

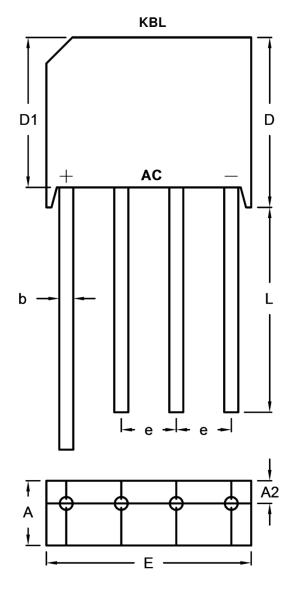
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PACKAGE OUTLINE DIMENSIONS



| DIM. | Unit (mm) | | Unit (| (inch) | |
|------|------------|-------|--------|--------|--|
| | Min. | Max. | Min. | Max. | |
| A | 5.50 | 6.50 | 0.217 | 0.256 | |
| A2 | 2.10 (TYP) | | 0.083 | (TYP) | |
| b | 1.20 | 1.40 | 0.047 | 0.055 | |
| D | 15.20 | 16.30 | 0.598 | 0.642 | |
| D1 | 13.70 | 14.10 | 0.539 | 0.555 | |
| E | 18.50 | 19.50 | 0.728 | 0.768 | |
| е | 4.60 | 5.60 | 0.181 | 0.220 | |
| L | 19.00 | - | 0.748 | - | |

MARKING DIAGRAM



| P/N | = Marking Code |
|-----|----------------|
| YWW | = Date Code |

F = Factory Code



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